SN74LS132

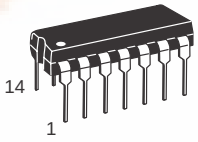
Quad 2-Input Schmitt Trigger NAND Gate

The SN74LS132 contains four 2-Input NAND Gates which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Additionally, they have greater noise margin than conventional NAND Gates.

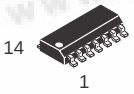
Each circuit contains a 2-input Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations. As long as one input remains at a more positive voltage than V_{T+} (MAX), the gate will respond to the transitions of the other input as shown in Figure 1.

ON Semiconductor
Formerly a Division of Motorola
http://onsemi.com

LOW POWER SCHOTTKY

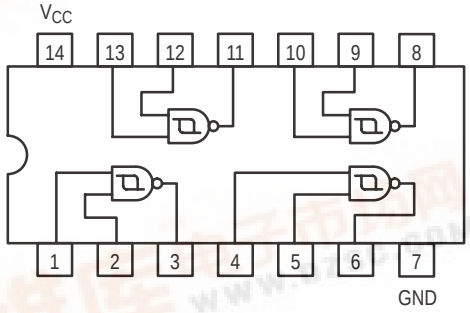


PLASTIC
N SUFFIX
CASE 646



SOIC
D SUFFIX
CASE 751A

LOGIC AND CONNECTION DIAGRAM
DIP (TOP VIEW)



GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			–0.4	mA
I_{OL}	Output Current – Low			8.0	mA

ORDERING INFORMATION

Device	Package	Shipping
SN74LS132N	14 Pin DIP	2000 Units/Box
SN74LS132D	14 Pin	2500/Tape & Reel

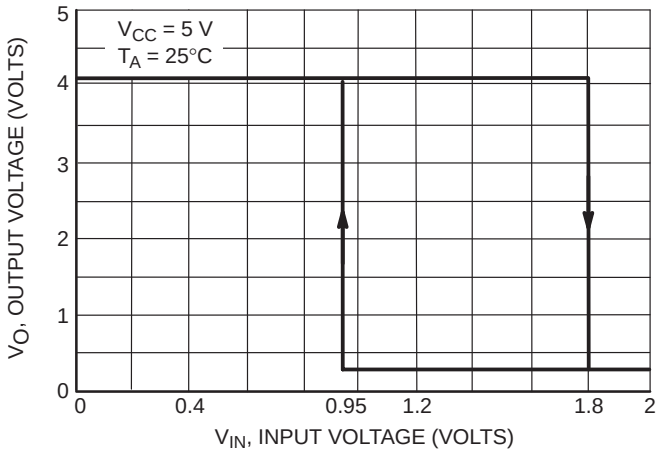


Figure 1. V_{IN} versus V_{OUT} Transfer Function

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
V_{T+}	Positive-Going Threshold Voltage	1.5		2.0	V	V_{CC} = 5.0 V
V_{T-}	Negative-Going Threshold Voltage	0.6		1.1	V	V_{CC} = 5.0 V
$V_{T+} - V_{T-}$	Hysteresis	0.4	0.8		V	V_{CC} = 5.0 V
V_{IK}	Input Clamp Diode Voltage		−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	2.7	3.4		V	V_{CC} = MIN, I_{OH} = −400 μA, V_{IN} = V_{IL}
V_{OL}	Output LOW Voltage		0.25	0.4	V	V_{CC} = MIN, I_{OL} = 4.0 mA, V_{IN} = 2.0 V
			0.35	0.5	V	V_{CC} = MIN, I_{OL} = 8.0 mA, V_{IN} = 2.0 V
I_{T+}	Input Current at Positive-Going Threshold		−0.14		mA	V_{CC} = 5.0 V, V_{IN} = V_{T+}
I_{T-}	Input Current at Negative-Going Threshold		−0.18		mA	V_{CC} = 5.0 V, V_{IN} = V_{T-}
I_{IH}	Input HIGH Current			20	μA	V_{CC} = MAX, V_{IN} = 2.7 V
				0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V
I_{IL}	Input LOW Current			−0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V
I_{OS}	Output Short Circuit Current (1)	−20		−100	mA	V_{CC} = MAX, V_{OUT} = 0 V
I_{CC}	Power Supply Current Total, Output HIGH		5.9	11	mA	V_{CC} = MAX, V_{IN} = 0 V
	Total, Output LOW		8.2	14	mA	V_{CC} = MAX, V_{IN} = 4.5 V

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
t_{PLH}	Turn-Off Delay, Input to Output			22	ns	V_{CC} = 5.0 V C_L = 15 pF
t_{PHL}	Turn-On Delay, Input to Output			22	ns	

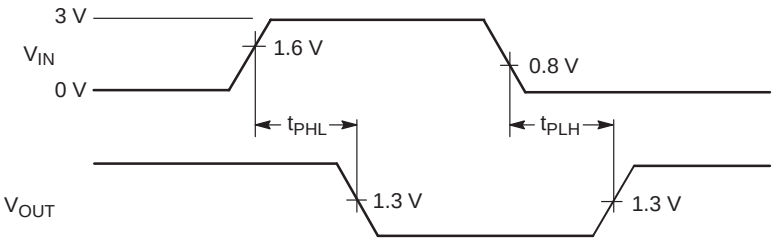


Figure 2. AC Waveforms

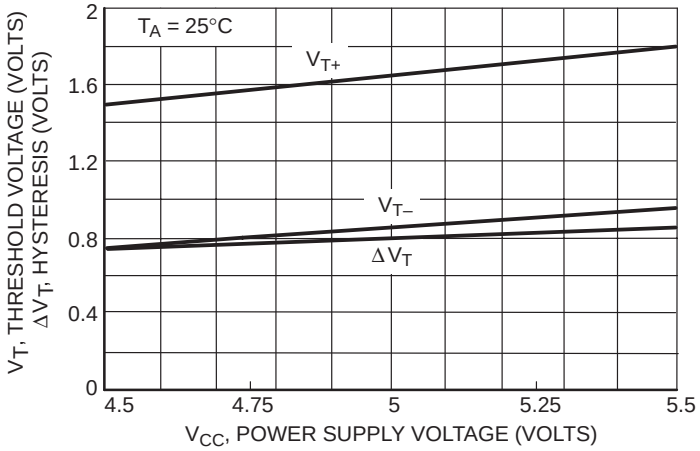


Figure 3. Threshold Voltage and Hysteresis versus Power Supply Voltage

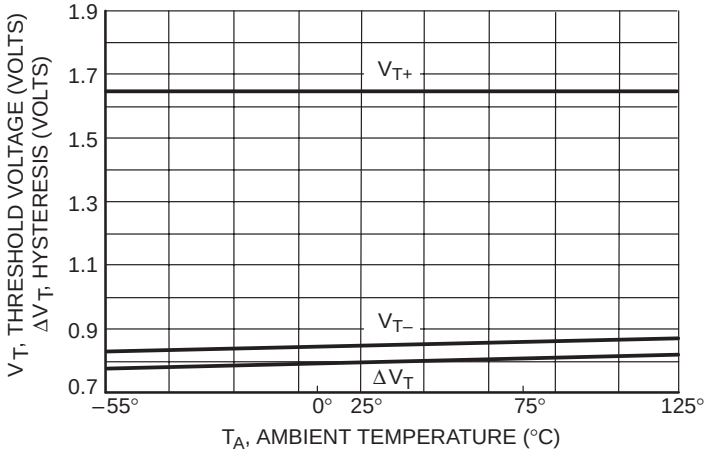
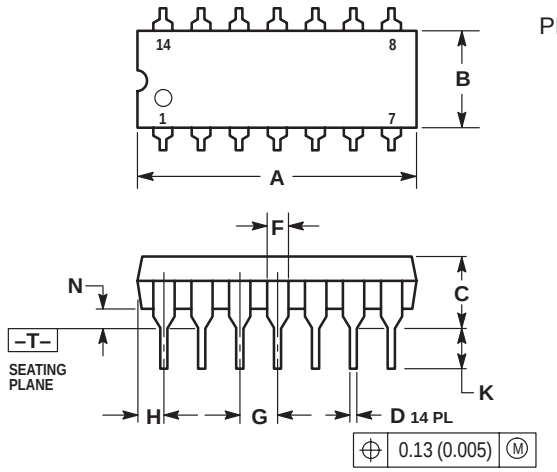


Figure 4. Threshold Voltage and Hysteresis versus Temperature

PACKAGE DIMENSIONS

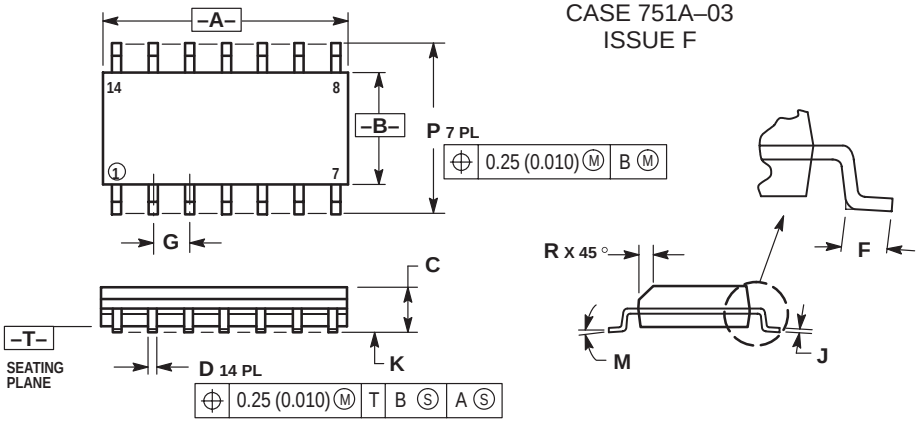
N SUFFIX
PLASTIC PACKAGE
CASE 646–06
ISSUE M



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	—	10°	—	10°
N	0.015	0.039	0.38	1.01

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751A–03
ISSUE F



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

PUBLICATION ORDERING INFORMATION

North America Literature Fulfillment:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada
Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support
German Phone: (+1) 303–308–7140 (M–F 2:30pm to 5:00pm Munich Time)
Email: ONlit–german@hibbertco.com
French Phone: (+1) 303–308–7141 (M–F 2:30pm to 5:00pm Toulouse Time)
Email: ONlit–french@hibbertco.com
English Phone: (+1) 303–308–7142 (M–F 1:30pm to 5:00pm UK Time)
Email: ONlit@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support
Phone: 303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time)
Toll Free from Hong Kong 800–4422–3781
Email: ONlit–asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center
4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–8549
Phone: 81–3–5487–8345
Email: r14153@onsemi.com

Fax Response Line: 303–675–2167
800–344–3810 Toll Free USA/Canada

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.